



**DUAL N-CHANNEL ENHANCEMENT MODE MOSFET** 

### Product Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
60V	7.5Ω @ V <sub>GS</sub> = 5V	0.23A

This MOSFET is designed to meet the stringent requirements of

automotive applications. It is qualified to AEC-Q101, supported by a

### **Features and Benefits**

- **Dual N-Channel MOSFET**
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 2N7002DWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Lead-Frame (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (e3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)





### Ordering Information (Note 4)

**Description and Applications** 

**Power Management Functions** 

PPAP, and is ideal for use in:

Motor Control

Part Number	Case	Packaging
2N7002DWQ-7-F	SOT363	3,000/Tape & Reel
2N7002DWQ-13-F	SOT363	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### Marking Information

$\square$		
K72	ΥM	
MY	K72	

K72 = Product Type Marking Code YM = Date Code Marking

Top View Internal Schematic

Y or  $\overline{Y}$ = Year (ex: I = 2021)

M = Month (ex: 9 = September)

#### Date Code Key

Year	1998		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	J			J	K	L	М	Ν	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



### Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Prain-Gate Voltage $R_{GS}$ ≤ 1.0MΩ			V <sub>DGR</sub>	60	V
	Co	ntinuous	V <sub>GSS</sub>	±20	V
Gate-Source Voltage		Pulsed	V <sub>GSS</sub>	±40	V
Continuous Drain Current (Note 6) $V_{GS}$ = 5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ $T_A = +100^{\circ}C$	ID	0.23 0.18 0.14	A
Maximum Continuous Body Diode Forward Current (Note 6)			Is	0.23	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	0.8	A

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

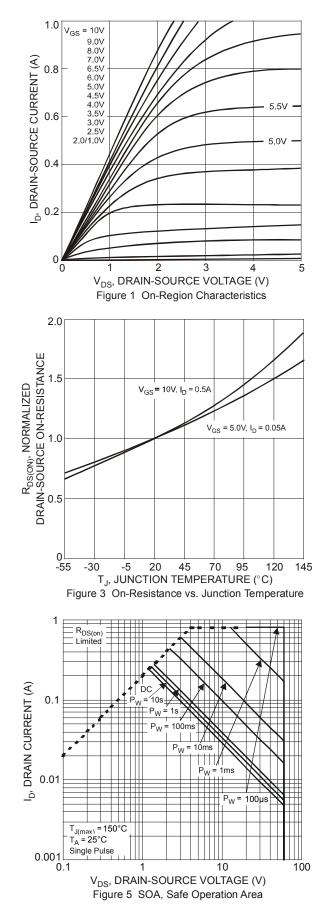
Characteristic		Symbol	Value	Unit
	T <sub>A</sub> = +25°C		0.31	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	PD	0.2	W
	T <sub>A</sub> = +100°C		0.12	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ hetaJA}$	410	°C/W
	T <sub>A</sub> = +25°C		0.4	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	PD	0.25	W
	T <sub>A</sub> = +100°C		0.15	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ hetaJA}$	318	°C/W
Thermal Resistance, Junction to Case (Note 6)	Steady State	$R_{ ext{ heta}JC}$	135	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

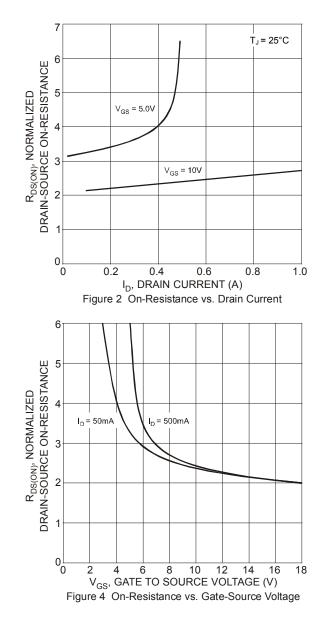
### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					-	-	
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	60	70		V	$V_{GS}$ = 0V, $I_{D}$ = 10 $\mu$ A
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = +25°C @ T <sub>C</sub> = +125°C	I <sub>DSS</sub>	_	_	1.0 500	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V
Gate-Body Leakage		IGSS			±10	nA	$V_{GS}$ = ±20V, $V_{DS}$ = 0V
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage		V <sub>GS(TH)</sub>	1.0		2.0	V	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A
Static Drain-Source On-Resistance	@ T <sub>J</sub> = +25°C	<b>D</b>	_	3.2 4.4	7.5	Ω	V <sub>GS</sub> = 5.0V, I <sub>D</sub> = 0.05A
	@ T <sub>J</sub> = +125°C	R <sub>DS(ON)</sub>			13.5		V <sub>GS</sub> = 10V, I <sub>D</sub> = 0.5A
On-State Drain Current		I <sub>D(ON)</sub>	0.5	1.0		А	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 7.5V
Forward Transconductance		<b>g</b> fs	80			mS	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.2A
Diode Forward Voltage		V <sub>SD</sub>		0.78	1.5	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 115mA
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance		Ciss		22	50	рF	
Output Capacitance		Coss		11	25	pF	$V_{DS} = 25V, V_{GS} = 0V$
Reverse Transfer Capacitance		Crss	_	2.0	5.0	рF	f = 1.0MHz
Turn-On Delay Time		t <sub>D(ON)</sub>	_	7.0	20		V <sub>DD</sub> = 30V, I <sub>D</sub> = 0.2A,
Turn-Off Delay Time		t <sub>D(OFF)</sub>		11.0	20	ns	R <sub>L</sub> = 150Ω, V <sub>GEN</sub> = 10V, R <sub>GEN</sub> = 25Ω

 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing. Notes:



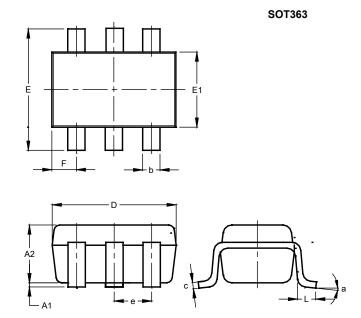






# Package Outline Dimensions

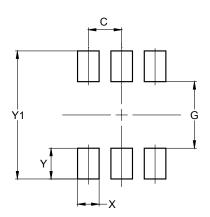
Please see http://www.diodes.com/package-outlines.html for the latest version.



		T262								
	SOT363									
Dim	Min	Max	Тур							
A1	0.00	0.10	0.05							
A2	0.90	1.00	0.95							
b	0.10	0.30	0.25							
С	0.10	0.22	0.11							
D	1.80	2.20	2.15							
Е	2.00	2.20	2.10							
E1	1.15	1.35	1.30							
е	C	.650 E	SC							
F	0.40	0.45	0.425							
L	0.25	0.40	0.30							
а	0°	8°								
All I	Dimen	sions	in mm							

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value
	(in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500

SOT363



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